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BUX98A

High power NPN transistor

Features

- High voltage capability
- High current capability
- Fast switching speed

Applications

- High frequency and efficency converters
- Linear and switching industrial equipment

Description

The BUX98A is a multi-epitaxial mesa NPN transistor in TO-3 metal case, intended for industrial applications from single and three-phase mains operation.

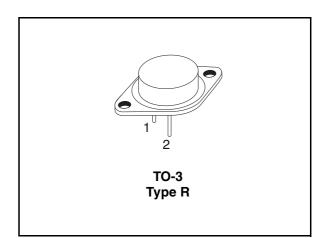


Figure 1. Internal schematic diagram

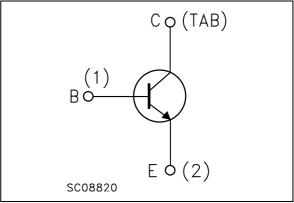


Table 1. Device summary

Order codes	Marking	Package	Packaging
BUX98A	BUX98A	TO-3	Tray

November	2008

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CER}	Collector-emitter voltage ($R_{BE} \le 10 \Omega$)	1000	V
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	1000	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	450	V
V _{EBO}	Emitter-base voltage ($I_{\rm C} = 0$)	7	V
۱ _C	Collector current	30	А
I _{CM}	Collector peak current ($t_p \le 5ms$)	60	А
I _{CP}	Collector peak current non repetitive (t_p \leq 20 $\mu s)$	80	А
Ι _Β	Base current	8	А
I _{BM}	Base peak current (t _p ≤5ms)	30	А
P _{TOT}	Total power dissipation at $T_c = 25 \ ^{\circ}C$	250	W
T _{stg}	Storage temperature	-65 to 200	°C
TJ	Max. operating junction temperature	200	U

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max.	0.7	°C/W

2 Electrical characteristics

(T_{case} = 25 °C; unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 1000 V V _{CE} = 1000 V T _C = 125 °C			400 4	μA mA
I _{CER}	Collector cut-off current (R _{BE} = 10 Ω)	V _{CE} = 1000 V V _{CE} = 1000 V T _C = 125 °C			1 8	μΑ μΑ
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} = 1000 V			2	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V			2	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage $(I_B = 0)$	I _C = 200 mA	450			V
V _{CER(sus)} ⁽¹⁾	Collector-emitter sustaining voltage ($R_{BE} = 10 \Omega$)	I _C = 1 A L= 2 mH	1000			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = 16 \text{ A}$ $I_{B} = 3.2 \text{ A}$ $I_{C} = 24 \text{ A}$ $I_{B} = 5 \text{ A}$			1.5 5	V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_{\rm C} = 16 {\rm A}$ $I_{\rm B} = 3.2 {\rm A}$			1.6	V
t _{on} t _s t _f	Resistive load Turn-on time Storage time Fall time	$I_{C} = 16 \text{ A}$ $V_{CC} = 150 \text{ V}$ $I_{B(on)} = -I_{B(off)} = 3.2 \text{ A}$			1 3 0.8	μs μs μs

Table 4.	Electrical	characteristics
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1. Pulsed duration = 300 μ s, duty cycle \leq 1.5%



Electrical characteristics (curves) 2.1

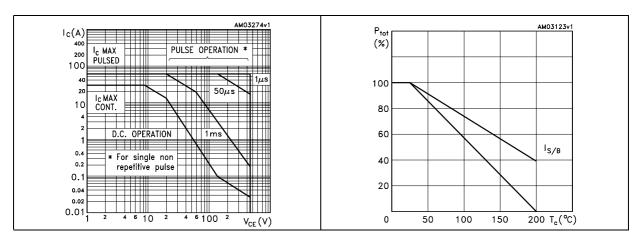


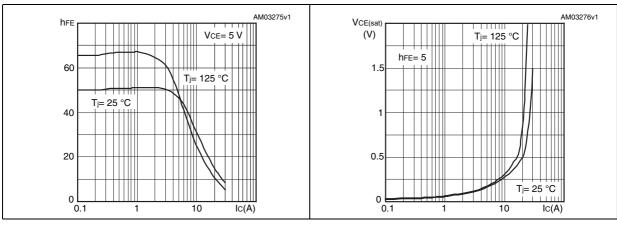
Figure 3.

Figure 5.

Figure 7.

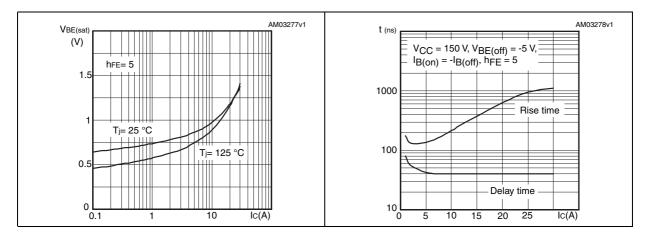
Figure 2. Safe operating area

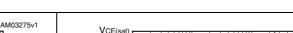
Figure 4. DC current gain



Base-emitter saturation voltage Figure 6.

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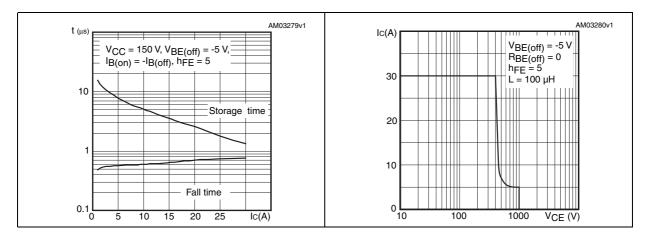
Collector-emitter saturation voltage

Resistive load switching times (on)

Derating curve

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Figure 8. Resistive load switching times (off) Figure 9. Reverse biased SOA





3 Test circuits

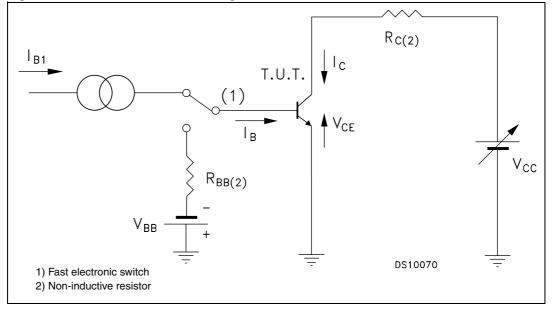


Figure 10. Resistive load switching test circuit



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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	TO-3 type R Mechanical data					
DIM.		mm			inch	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А		11.7			0.460	
В	0.96		1.10	0.037		0.043
С			1.70			0.066
D			8.7			0.342
E			20.0			0.787
G		10.9			0.429	
Ν		16.9			0.665	
Р			26.2			1.031
R	3.88		4.09	0.152		0.161
U			39.50			1.555
V		30.10			1.185	



5 Revision history

Table 5.Document revision history

Date	Revision	Changes
21-Jun-2004	4	
24-Nov-2008	5	Inserted new Section 2.1: Electrical characteristics (curves)



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